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AMENDMENTS TO THE CLAIMS

1. (Currently Amended) A method for manufacturing a photomask blank having a film

of at least one layer formed on a substrate, comprising the steps of

forming a film on a synthetic quartz glass substrate, and

irradiating the entire surface of the film all at once with light from a flash lamp, wherein

the film is a phase shift film, a light-shielding film or an antireflection film, and an

intensity of the irradiation is in a range of 0.1 to 100 1 to 50 J/cm² and a duration of the

irradiation is up to 1 second.

2. (Original) The method of claim 1 wherein the step of forming a film on a substrate

includes sputtering.

3. (Original) The method of claim 1 wherein the film of at least one layer has a lower

light transmittance than the substrate.

4. (Original) The method of claim 1 wherein the film is a phase shift film.

5. (Original) The method of claim 4 wherein said phase shift film contains silicon, at

least one metal other than silicon, and at least one element selected from the group consisting of

oxygen, carbon and nitrogen.

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Amendment dated September 29, 2006

Reply to Office Action of July 18, 2006

6. (Original) A method for manufacturing a photomask comprising the steps of:

forming a patterned resist on the film on the photomask blank manufactured by the

method of claim 1, by photolithography,

etching away those portions of the film which are not covered with the resist, and

removing the resist.

7-18. (Cancelled).

19. (Previously Presented) The method of claim 1, wherein the step of irradiation

converts compressive stresses to tensile stresses and thus reduces warpage in the photomask

blank compared to a photomask blank not subjected to said irradiation.

20. (Previously Presented) The method of claim 6, wherein the step of irradiation

converts compressive stresses to tensile stresses and thus reduces warpage in the photomask

compared to a photomask prepared without irradiation of the photomask blank.

21. (Cancelled).

22. (Previously Presented) The method of claim 1, wherein the step of irradiation

reduces stresses in the film and thus reduces warpage in the photomask blank compared to a

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photomask blank not subjected to said irradiation.

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23. (Previously Presented) The method of claim 6, wherein the step of irradiation

reduces stresses in the film and thus reduces warpage in the photomask blank compared to a

photomask blank not subjected to said irradiation.

24. (Cancelled).

25. (New) The method of claim 1, wherein the intensity of the irradiation is in a range of

10 to 50 J/cm².

26. (New) The method of claim 1, wherein the duration of the irradiation is up to 0.1

second.

27. (New) The method of claim 1, wherein the duration of the irradiation

is up to 0.01 second.

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